

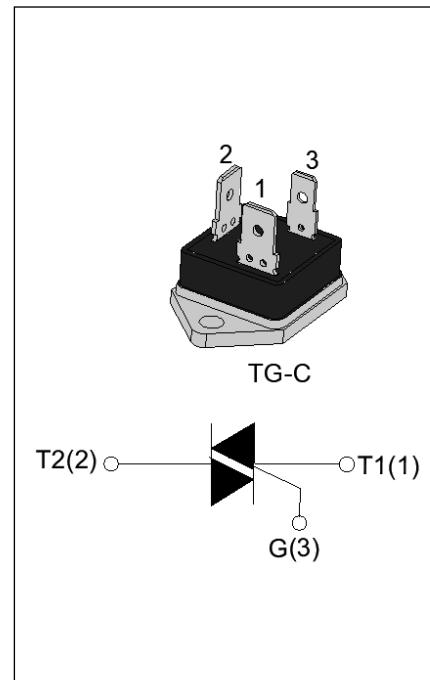


JST41T-600B 40A TRIAC

Rev.A.1.0

DESCRIPTION:

The JST41T-600B triac is suitable for general purpose AC switching. It can be used as an ON/OFF function in applications such as heating regulation, induction motor starting circuits, for phase control operation in light dimmers, motor speed controllers. By using a DBC, JST41T-600B provides a rated insulation voltage of 2500 VRMS, complying with UL standards (File ref: E252906). Package TG-C is RoHS compliant.

**MAIN FEATURES**

Symbol	Value	Unit
$I_{T(RMS)}$	40	A
V_{DRM}/V_{RRM}	600	V
$I_{GT\text{ I/II/III/IV}}$	50/50/50/70	mA

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Storage junction temperature range	T_{stg}	-40-150	°C
Operating junction temperature range	T_j	-40-125	°C
Repetitive peak off-state voltage ($T_j=25^\circ\text{C}$)	V_{DRM}	600	V
Repetitive peak reverse voltage ($T_j=25^\circ\text{C}$)	V_{RRM}	600	V
RMS on-state current ($T_c \leqslant 89^\circ\text{C}$)	$I_{T(RMS)}$	40	A
Non repetitive surge peak on-state current (full cycle , $t_p=20\text{ms}$, $T_j=25^\circ\text{C}$)	I_{TSM}	420	A
Non repetitive surge peak on-state current (full cycle , $t_p=16.6\text{ms}$, $T_j=25^\circ\text{C}$)		462	
I^2t value for fusing ($t_p=10\text{ms}$, $T_j=25^\circ\text{C}$)	I^2t	1000	A^2s
Critical rate of rise of on-state current ($I_G=2 \times I_{GT}$, $f=100\text{Hz}$, $T_j=125^\circ\text{C}$)	dI/dt	100	$\text{A}/\mu\text{s}$
		50	
Peak gate current ($t_p=20\mu\text{s}$, $T_j=125^\circ\text{C}$)	I_{GM}	8	A
Average gate power dissipation ($T_j=125^\circ\text{C}$)	$P_{G(AV)}$	1	W
Peak gate power	P_{GM}	40	W

Peak pulse voltage ($T_j=25^\circ\text{C}$; non-repetitive, off-state; FIG.7)	V_{pp}	0.9	kV
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ELECTRICAL CHARACTERISTICS ($T_j=25^\circ\text{C}$ unless otherwise specified)

Symbol	Test Condition	Quadrant	Value		Unit
I_{GT}	$V_D=12\text{V}$ $R_L=33\Omega$	I - II - III	MAX.	50	mA
		IV		70	
V_{GT}		ALL	MAX.	1.3	V
V_{GD}	$V_D=V_{DRM}$ $T_j=125^\circ\text{C}$ $R_L=3.3\text{K}\Omega$	ALL	MIN.	0.2	V
I_L	$I_G=1.2I_{GT}$	I - III - IV	MAX.	80	mA
		II		160	
I_H	$I_T=500\text{mA}$		MAX.	80	mA
dV/dt	$V_D=400\text{V}$ Gate Open $T_j=125^\circ\text{C}$		MIN.	1500	V/ μs
$(dV/dt)c$	$(dI/dt)c=20\text{A/ms}$, $T_j=125^\circ\text{C}$		MIN.	20	V/ μs
t_{on}	$I_G=80\text{mA}$ $I_A=400\text{mA}$ $I_R=40\text{mA}$ $T_j=25^\circ\text{C}$	TYP.	10	μs	
t_{off}			70		

STATIC CHARACTERISTICS

Symbol	Parameter		Value(MAX.)	Unit
V_{TM}	$I_{TM}=60\text{A}$	$t_p=380\mu\text{s}$	$T_j=25^\circ\text{C}$	1.4 V
V_{TO}	Threshold voltage		$T_j=125^\circ\text{C}$	0.73 V
R_D	Dynamic resistance		$T_j=125^\circ\text{C}$	10 m Ω
I_{DRM}	$V_D=V_{DRM}$ $V_R=V_{RRM}$		$T_j=25^\circ\text{C}$	5 μA
I_{RRM}			$T_j=125^\circ\text{C}$	3 mA

THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	junction to case (AC)	0.7	°C/W
$R_{th(j-a)}$	junction to ambient (AC)	50	°C/W

ORDERING INFORMATION

J	ST	41	T	-600	B
JieJie Microelectronics Co., Ltd.					
	Triacs				
		<u>I_{T(RMS)}:40A</u>			
			T:TG-C(Ins)		
					<u>B:I_{GT1-3}≤50mA I_{GT4}≤70mA</u>
					<u>600:V_{DRM} / V_{RRM}≥600V</u>

MARKING

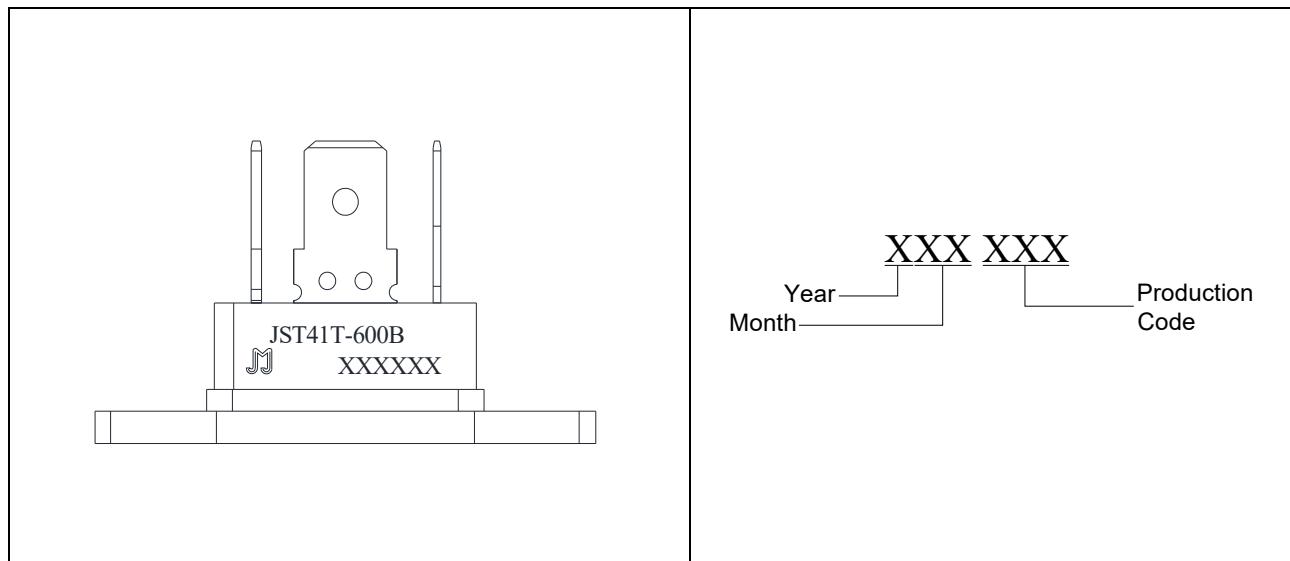


FIG.1 Maximum power dissipation versus RMS on-state current

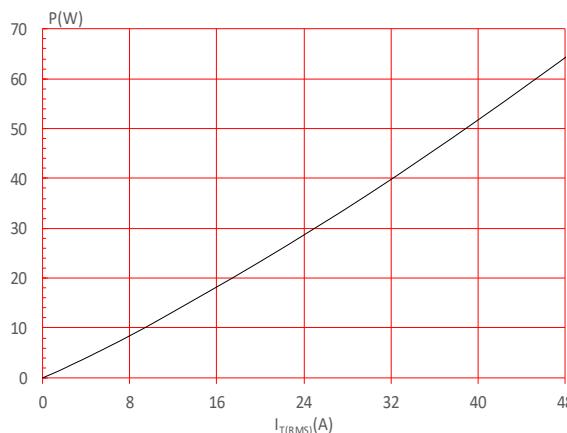


FIG.3: Surge peak on-state current versus number of cycles

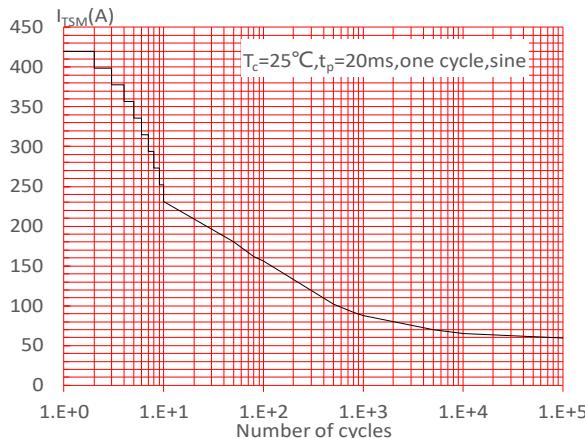


FIG.5: Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 20\text{ms}$, and corresponding value of I^2t
(I - II : $\text{d}I/\text{d}t < 100\text{A}/\mu\text{s}$; III-IV : $\text{d}I/\text{d}t < 50\text{A}/\mu\text{s}$)

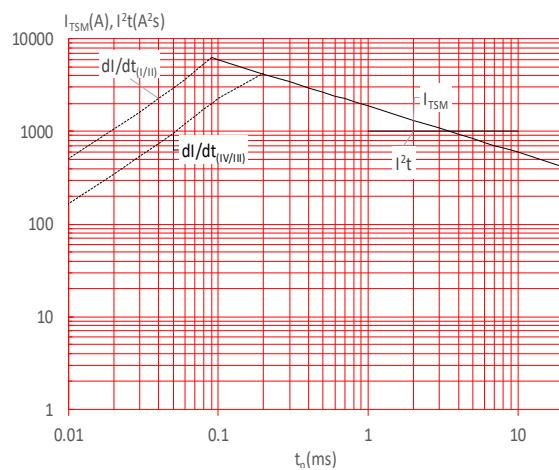


FIG.2: RMS on-state current versus case temperature

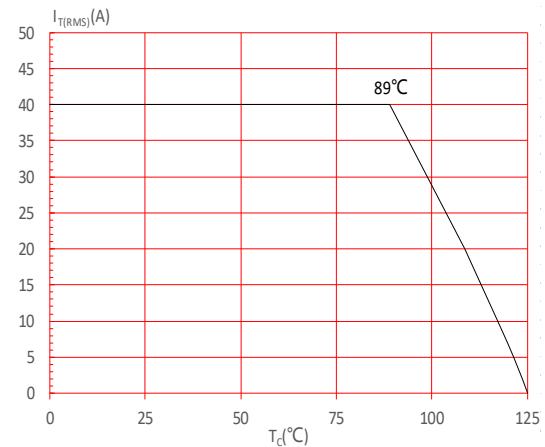


FIG.4: On-state characteristics

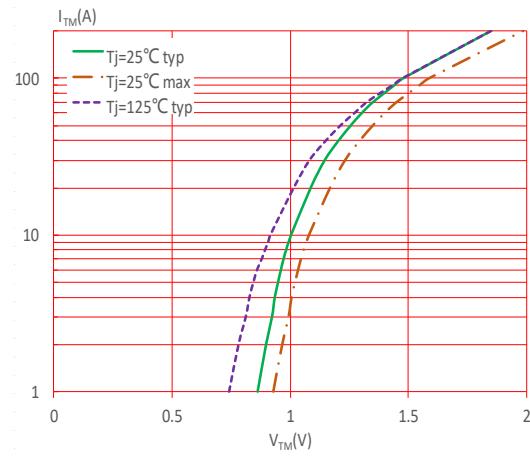


FIG.6: Relative variations of gate trigger current, holding current and latching current versus junction temperature

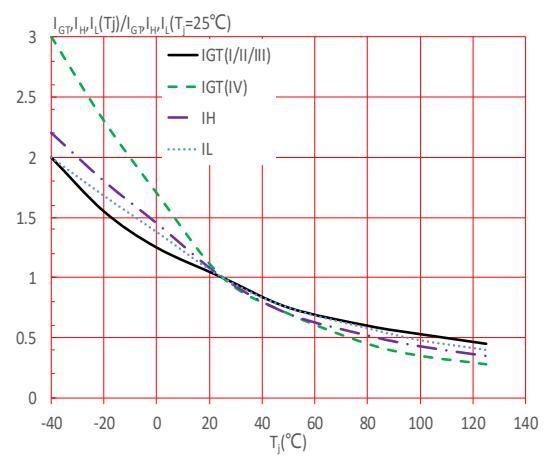
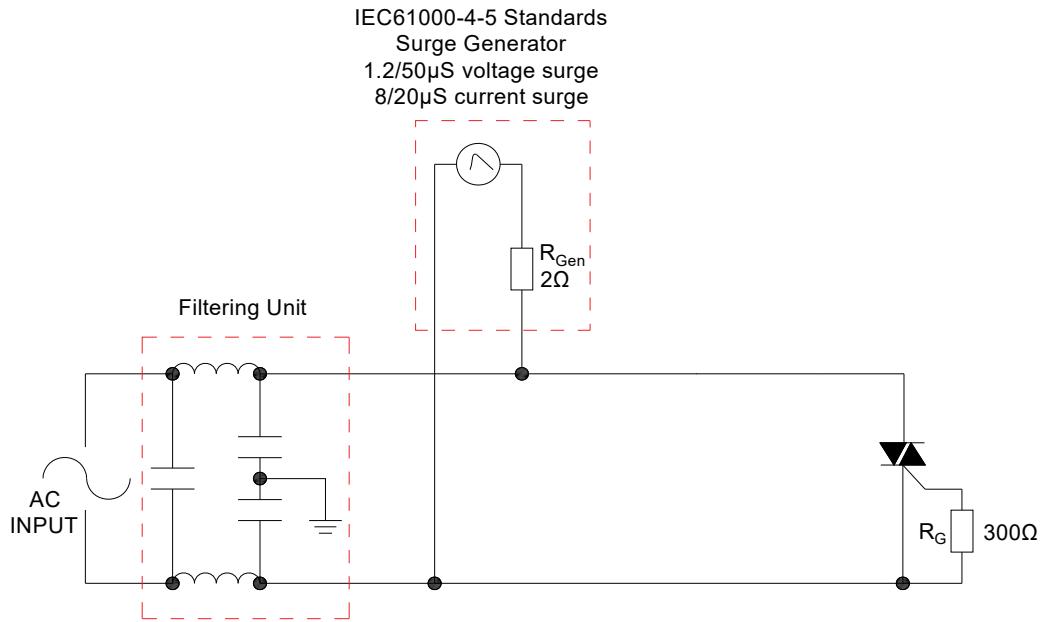


FIG.7: Test circuit for inductive and resistive loads to IEC-61000-4-5 standards



SHAPING AND SOLDERING PARAMETERS

Refer to 《Instructions for installation of plastic-sealed in-line power devices》 released by JieJie.

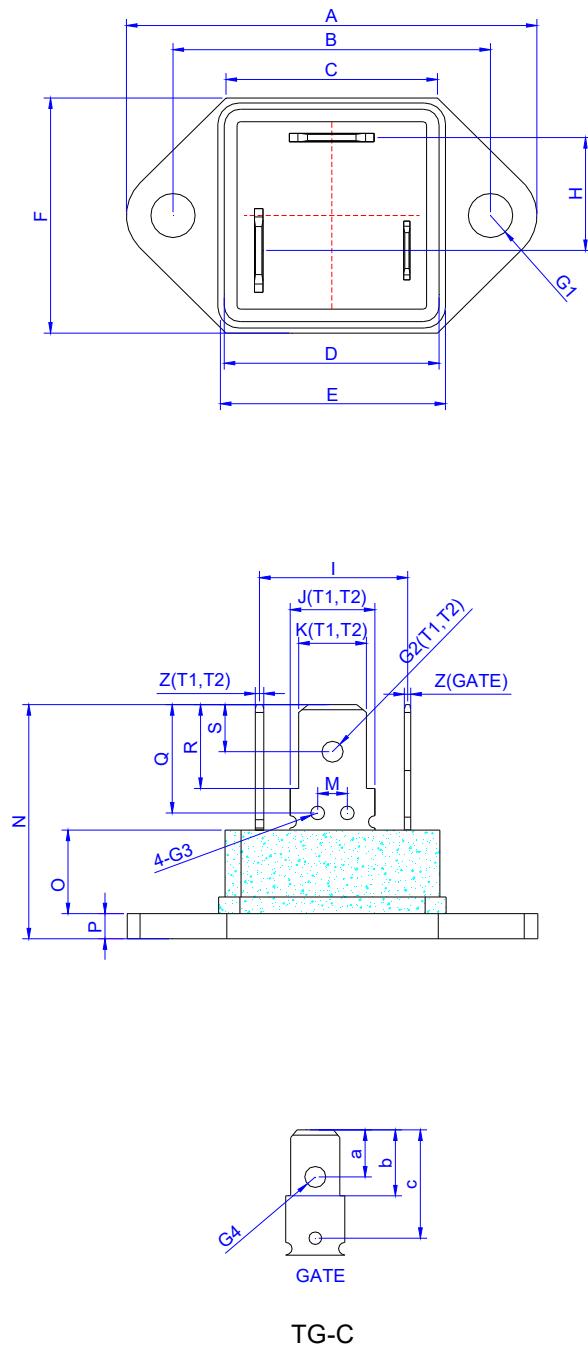
ORDERING INFORMATION

Order code	Voltage V_{DRM}/V_{RRM} (V)	IGT(mA)		Package	Base qty. (pcs)	Delivery mode
		I -II-III	IV			
JST41T-600B	600	50	70	TG-C(Ins)	10	Tube

Document Revision History

Date	Revision	Changes
Apr.14, 2023	A.1.0	Last updated

PACKAGE MECHANICAL DATA



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			39.2			1.543
B	29.8	30.0	30.2	1.173	1.181	1.189
C			20.2			0.795
D			20.5			0.807
E			21.6			0.85
F			23			0.905
G1	$\Phi 4.1$	$\Phi 4.2$	$\Phi 4.3$	$\Phi 0.161$	$\Phi 0.165$	$\Phi 0.169$
H		10.3			0.406	
I		13.9			0.547	
J(T1,T2)		8			0.315	
K(T1,T2)		6.4			0.252	
M	2.7	3.0	3.3	0.106	0.118	0.130
N			22.8			0.898
O		8.2			0.323	
P		2.5			0.098	
Q	9.45	9.75	10.1	0.374	0.383	0.398
R	7.8	7.95	8.1	0.307	0.313	0.319
S	4.3	4.5	4.7	0.169	0.177	0.185
Z(T1,T2)	0.78	0.8	0.85	0.0307	0.0315	0.0335
G2(T1,T2)		$\Phi 2$	$\Phi 2.2$		$\Phi 0.079$	$\Phi 0.087$
G3	$\Phi 1.1$	$\Phi 1.3$	$\Phi 1.5$	$\Phi 0.043$	$\Phi 0.051$	$\Phi 0.059$
G4		$\Phi 1.55$	$\Phi 1.75$		$\Phi 0.061$	$\Phi 0.069$
a	2.95	3.15	3.35	0.116	0.124	0.132
b	6.2	6.35	6.5	0.244	0.25	0.256
c	9.35	9.75	10	0.368	0.384	0.393
Z(GATE)	0.58	0.6	0.65	0.0228	0.0236	0.0256
J(GATE)		5.6			0.221	
K(GATE)		4.65			0.183	

DELIVERY MODE

PACKAGE	OUTLINE	TUBE (PCS)	INNER BOX (PCS)	PER CARTON (PCS)
TG-C	TUBE	10	100	500

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